

Silicon NPN epitaxial planer type

■ Features

- Low noise figure NF.
- High gain.
- High transition frequency f_T .
- Mini Power type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	15	V
Collector to emitter voltage	V_{CEO}	10	V
Emitter to base voltage	V_{EBO}	2	V
Collector current	I_C	80	mA
Collector power dissipation	P_C^*	1	W
Junction temperature	T_j	150	$^{\circ}\text{C}$
Storage temperature	T_{stg}	$-55 \sim +150$	$^{\circ}\text{C}$

Unit: mm

Top View Dimensions:

- Overall width: 4.5 ± 0.1
- Internal width: 1.6 ± 0.2
- Left side height: 2.6 ± 0.1
- Left side angle: 45°
- Right side height: 4.0 ± 0.26
- Right side width: 0.4 max.
- Bottom left width: 0.4 ± 0.08
- Bottom left width: 0.5 ± 0.08
- Bottom left width: 1.5 ± 0.1
- Bottom center width: 3.0 ± 0.15
- Bottom right width: 1.0 ± 0.2

Side View Dimensions:

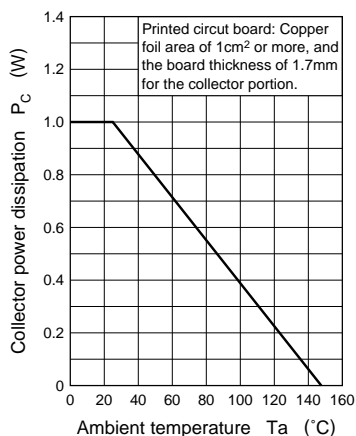
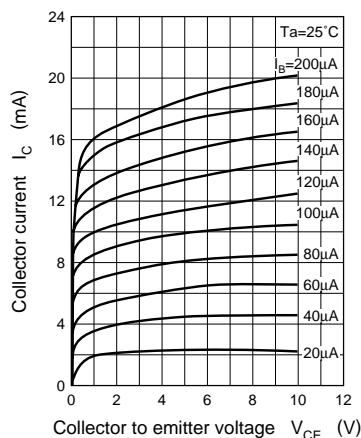
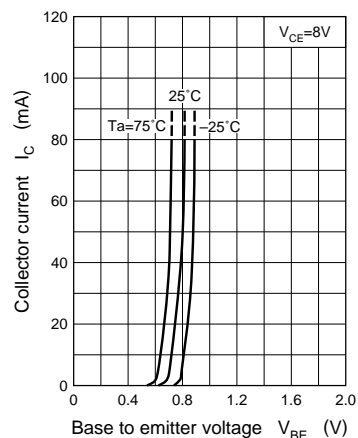
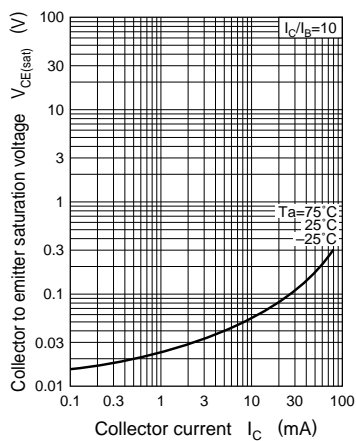
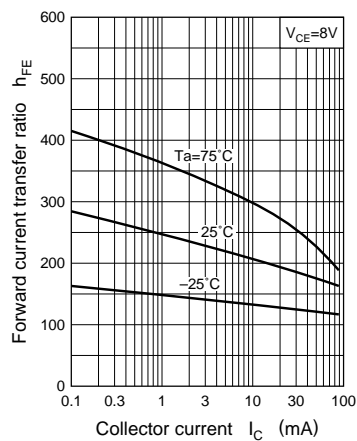
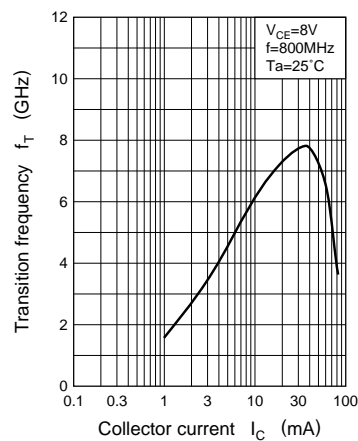
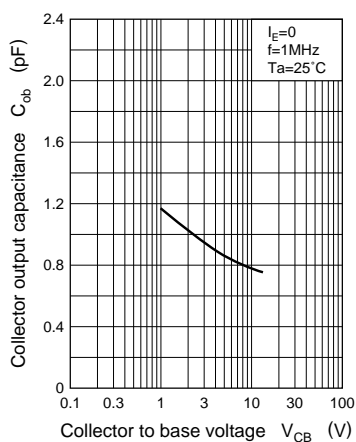
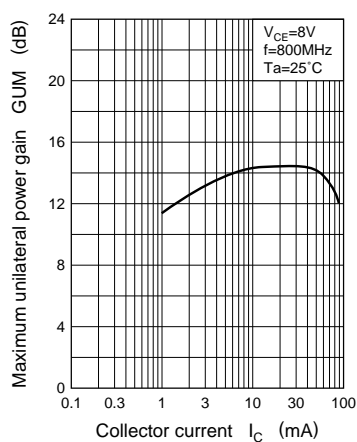
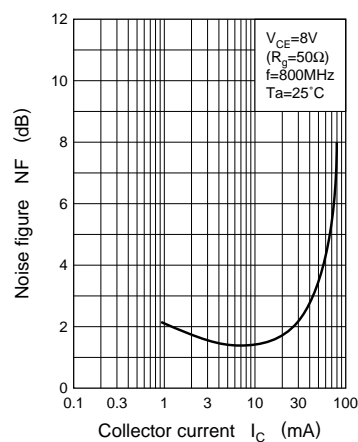
- Top width: 1.5 ± 0.1
- Bottom width: 0.4 ± 0.04
- Height: 2.5 ± 0.1

Base View Dimensions:

- Pin 3 (Base)
- Pin 2 (Collector)
- Pin 1 (Emitter)
- Marking

Marking symbol : W

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 10V, I_E = 0$			1	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = 2V, I_C = 0$			1	μA
Collector to base voltage	V_{CBO}	$I_C = 10\mu A, I_E = 0$	15			V
Collector to emitter voltage	V_{CEO}	$I_C = 100\mu A, I_B = 0$	10			V
Forward current transfer ratio	h_{FE}	$V_{CE} = 8V, I_C = 20mA$	80		250	
Transition frequency	f_T	$V_{CE} = 8V, I_C = 20mA, f = 800MHz$	5	6		GHz
Collector output capacitance	C_{ob}	$V_{CB} = 10V, I_E = 0, f = 1MHz$		0.9	1.2	pF
Foward transfer gain	$ S_{21e} ^2$	$V_{CE} = 8V, I_C = 20mA, f = 800MHz$	7.5	10		dB
Maximum unilateral power gain	GUM	$V_{CE} = 8V, I_C = 20mA, f = 800MHz$		11.5		dB
Noise figure	NF	$V_{CE} = 8V, I_C = 20mA, f = 800MHz$		1.7		dB

$P_C - T_a$  $I_C - V_{CE}$  $I_C - V_{BE}$  $V_{CE(sat)} - I_C$  $h_{FE} - I_C$  $f_T - I_C$  $C_{ob} - V_{CB}$  $GUM - I_C$  $NF - I_C$ 

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